

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L10	135407	(oxide near3 nitride near3 oxide) ONO	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/18 16:49
L11	3713	double near gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/18 16:49
L12	1607833	memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/18 18:03
L13	543	L10 and L11 and L12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/18 16:49
L14	516	L13 and (@ad<"20030514" @rlad<"20030514")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/18 16:49
L15	1724	(gate near insulating) with ((oxide near3 nitride near3 oxide) ONO)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/18 16:49
L16	1460	L15 and (@ad<"20030514" @rlad<"20030514")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/18 18:03
L20	276	SONOS near memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/18 18:03
L21	216	20 and (@ad<"20030514" @rlad<"20030514")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/18 18:04

L22	198	21 and 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/18 18:04
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